

**1N6356 thru  
1N6372  
and  
MPT-5 thru  
MPT-45C**

**FEATURES**

- DESIGNED TO PROTECT BIPOLAR AND MOS MICROPROCESSOR BASED SYSTEMS.
- VOLTAGE RANGE OF 5.0 TO 45 VOLTS
- LOW CLAMPING RATIO

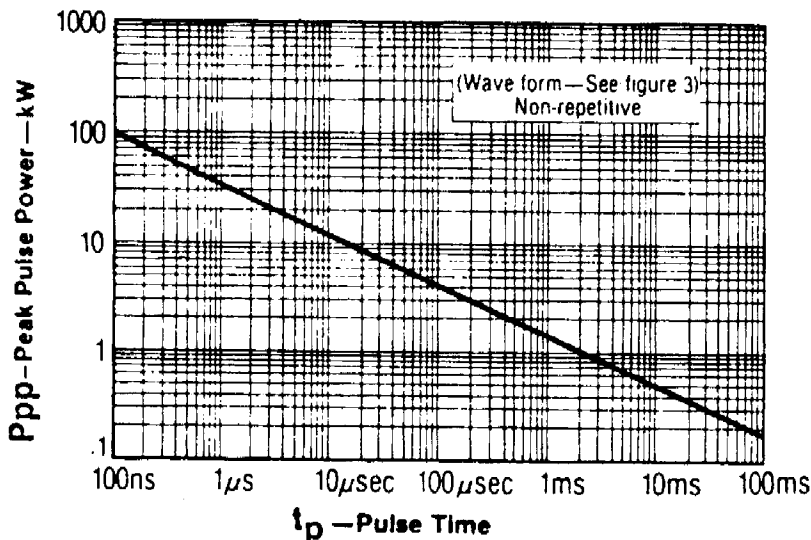
**MAXIMUM RATINGS**

1500 Watts of Peak Pulse Power dissipation at 25°C at 10/1000  $\mu$ s  
 $t_{\text{clamping}}$  (0 volts to  $V_{(BR)}$  min): Unidirectional — Less than  $1 \times 10^{-12}$  seconds  
Bidirectional — Less than  $5 \times 10^{-9}$  seconds  
Operating and Storage temperatures: -65° to +175°C  
Forward surge rating: 200 amps, 1/120 second at 25°C  
(Applies to Unipolar or single direction only for 1N6356-1N6364)  
Steady State power dissipation: 1.0 watt  
Repetition rate (duty cycle): .01%

**ELECTRICAL CHARACTERISTICS**

Clamping Factor: 1.33 @ Full rated power  
1.20 @ 50% rated power

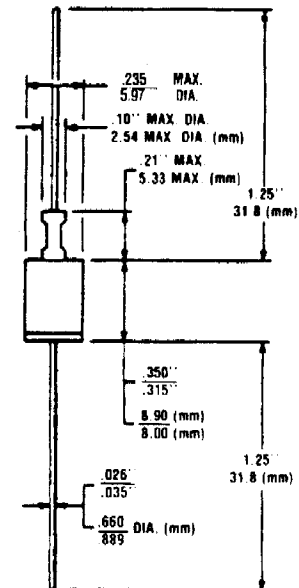
Clamping Factor: The ratio of the actual  $V_C$  (Clamping Voltage) to the actual  $V_{(BR)}$  (Breakdown Voltage) as measured on a specific device.



**FIGURE 1**  
PEAK PULSE POWER VS. PULSE TIME

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**TRANSIENT  
ABSORPTION ZENER**



**MECHANICAL  
CHARACTERISTICS**

CASE: DO-13 welded, hermetically sealed, metal and glass.

FINISH: All external surfaces are corrosion resistant and leads solderable.

POLARITY: Cathode connected to case and marked. Bidirectional not marked.

WEIGHT: 1.4 grams (Appx.)

MOUNTING POSITION: Any.

# 1N6356 thru 1N6372 and MPT-5 thru MPT-45C

## ELECTRICAL CHARACTERISTICS @ 25°C

MICROSEMI PART NUMBER	STAND-OFF VOLTAGE (NOTE 1) $V_{WM}$ VOLTS	MAXIMUM REVERSE LEAKAGE @ $V_{WM}$ $I_D$ $\mu A$	MINIMUM* BREAKDOWN VOLTAGE @ 1.0 mA $V_{BR}$ (min) VOLTS	MAXIMUM CLAMPING VOLTAGE (Fig. 2) $I_{PP1} = 1A$ $V_C$ VOLTS	MAXIMUM CLAMPING VOLTAGE (Fig. 2) @ $I_{PP2} = 10A$ $V_C$ VOLTS	MAXIMUM PEAK PULSE CURRENT $I_{PP3}$ A
1N6356 MPT-5	5.0	300	6.0	7.1	7.5	160
1N6357 MPT-8	8.0	25	9.4	11.3	11.5	100
1N6358 MPT-10	10.0	2	11.7	13.7	14.1	90
1N6359 MPT-12	12.0	2	14.1	16.1	16.5	70
1N6360 MPT-15	15.0	2	17.6	20.1	20.6	60
1N6361 MPT-18	18.0	2	21.2	24.2	25.2	50
1N6362 MPT-22	22.0	2	25.9	29.8	32.0	40
1N6363 MPT-36	36.0	2	42.4	50.6	54.3	23
1N6364 MPT-45	45.0	2	52.9	63.3	70.0	19

$V_f$  at 100 amps peak, 8.3 msec sine wave equals 3.5 volts maximum

## ELECTRICAL CHARACTERISTICS @ 25°C (Test Both Polarities)

1N6365 MPT-5C	5.0	300	6.0	7.1	7.5	160
1N6366 MPT-8C	8.0	25	9.4	11.4	11.6	100
1N6366 MPT-10C	10.0	2	11.7	14.1	14.5	90
1N6367 MPT-12C	12.0	2	14.1	16.7	17.1	70
1N6368 MPT-15C	15.0	2	17.6	20.8	21.4	60
1N6369 MPT-18C	18.0	2	21.2	24.8	25.5	50
1N6370 MPT-22C	22.0	2	25.9	30.8	32.0	40
1N6371 MPT-36C	36.0	2	42.4	50.6	54.3	23
1N6372 MPT-45C	45.0	2	52.9	63.3	70.0	19

C Suffix indicates Bidirectional

**NOTE 1** TAZ are normally selected according to the reverse "Stand Off Voltage" ( $V_{WM}$ ) which should be equal to or greater than the DC or continuous peak operating voltage level.

\*The minimum breakdown voltage as shown takes into consideration the  $\pm 1$  volt tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Similar devices are available with reduced clamping voltages where tighter regulated power supply voltages are employed.

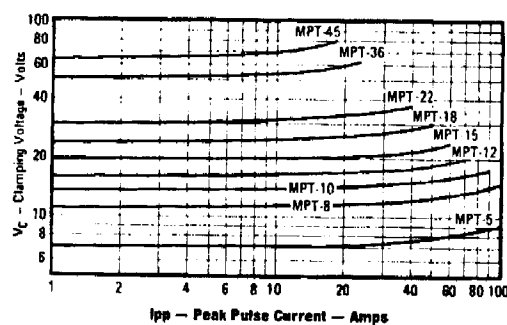


FIGURE 2  
Typical Characteristic Clamping Voltage  
vs. Peak Pulse Current

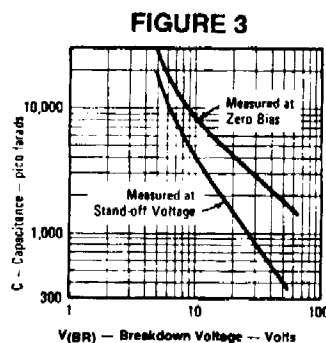


FIGURE 3  
Typical Capacitance vs. Breakdown Voltage  
(Unidirectional Types)

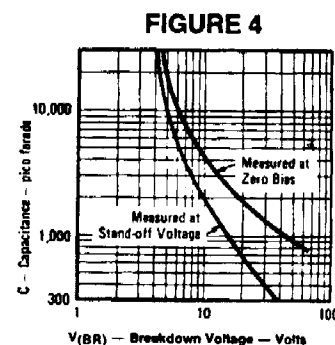


FIGURE 4  
Typical Capacitance vs. Breakdown Voltage  
(Bidirectional Types)